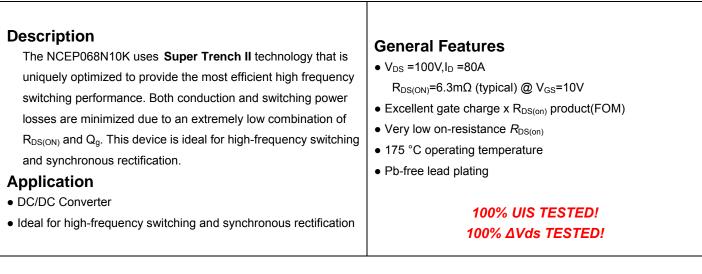
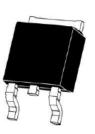
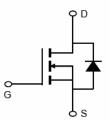


## NCE N-Channel Super Trench II Power MOSFET



TO-252-2L





#### Schematic Diagram

## Package Marking and Ordering Information

		- J			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP068N10K	NCEP068N10K	TO-252-2L	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	80	A
Drain Current-Continuous(T <sub>C</sub> =100 °C)	l <sub>D</sub> (100℃)	61	A
Pulsed Drain Current	I <sub>DM</sub>	320	A
Maximum Power Dissipation	PD	125	W
Derating factor		0.83	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	320	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>ejc</sub>	1.2	°C/W



## Electrical Characteristics (T<sub>c</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	····					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =10V, I <sub>D</sub> =40A	-	6.3	6.8	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =40A		60	-	S
Dynamic Characteristics (Note4)	· · ·					
Input Capacitance	C <sub>Iss</sub>		-	3600	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, F=1.0MHz	-	335	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	19.5	-	PF
Switching Characteristics (Note 4)	· · ·					
Turn-on Delay Time	t <sub>d(on)</sub>		-	16	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =50V,I <sub>D</sub> =40A	-	11	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	35	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	9	-	nS
Total Gate Charge	Qg		-	60	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =50V,I <sub>D</sub> =40A,	-	20		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	15		nC
Drain-Source Diode Characteristics	····					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-		1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	80	А
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =40A	-	70	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	137	-	nC

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

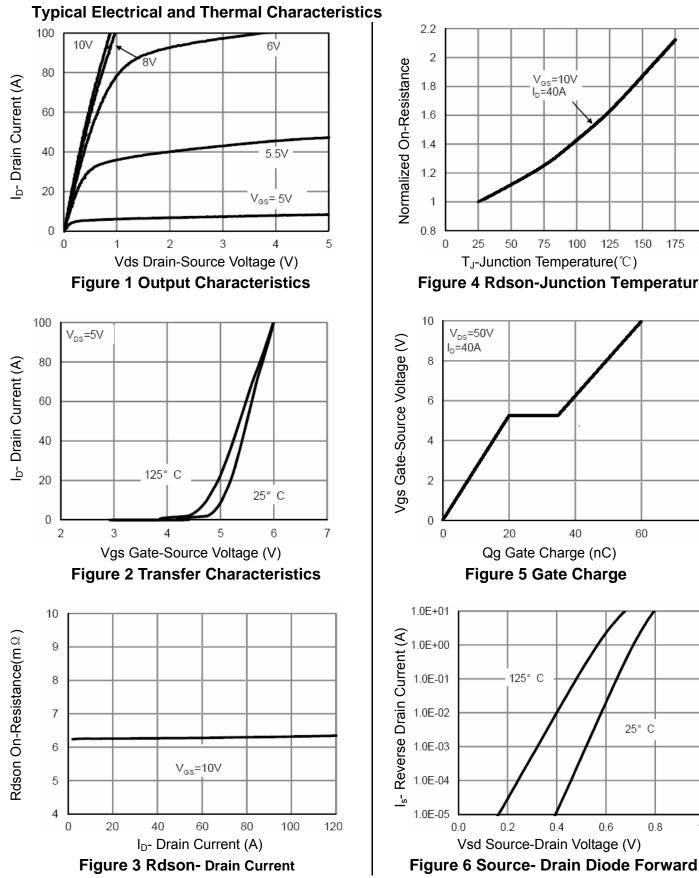
2. Surface Mounted on FR4 Board,  $t \le 10$  sec.

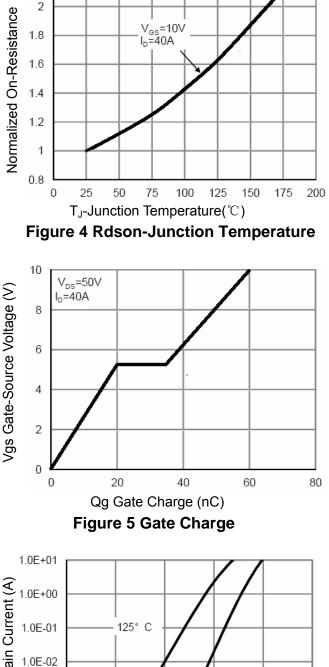
3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25  $^\circ \!\! C$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 







0.2

0.4

0.6

1.0

25° C

0.8



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# NCEP068N10K

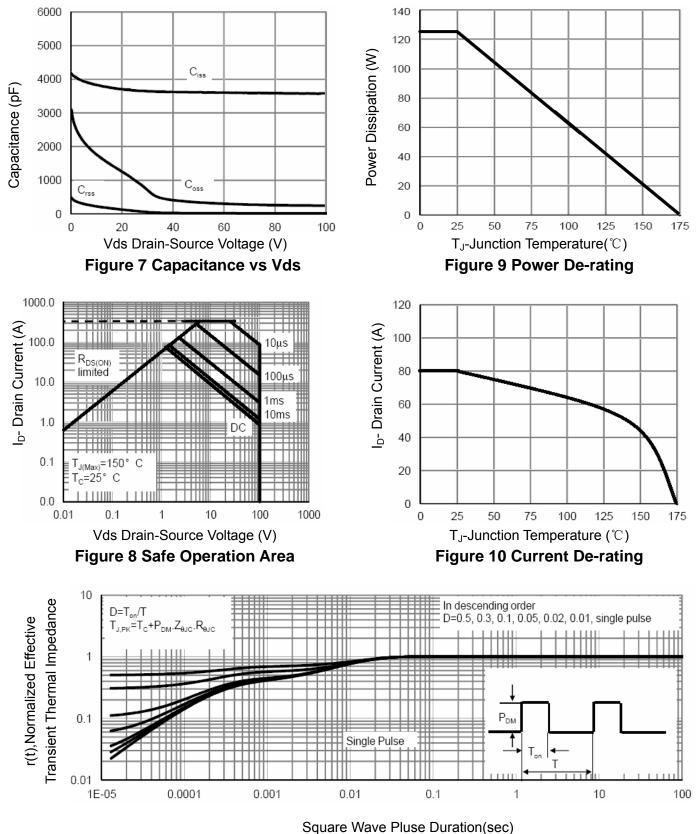
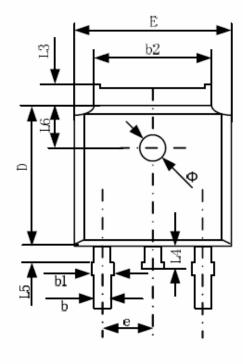
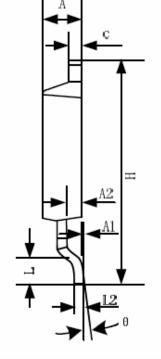


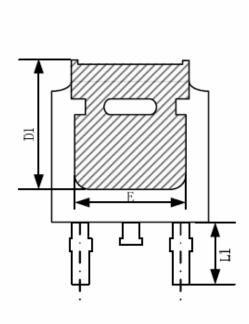
Figure 11 Normalized Maximum Transient Thermal Impedance



## **TO-252-2L Package Information**







Sumbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.20	2.38	0.087	0.094	
A1	0.00	0.10	0.000	0.004	
A2	0.90	1.10	0.035	0.043	
b	0.72	0.85	0.028	0.033	
b1	0.72	0.90	0.028	0.035	
b2	5.13	5.46	0.202	0.215	
с	0.47	0.60	0.019	0.024	
D	6.00	6.20	0.236	0.244	
D1	5.25		0.207		
E	6.50	6.70	0.256	0.264	
E1	4.70		0.185		
e	2.19	2.39	0.086	0.094	
н	9.80	10.40	0.386	0.409	
L	1.40	1.70	0.055	0.067	
L1	2.9	0 REF	0.114 REF		
L2	0.50	08 BSC	0.020 BSC		
L3	0.90	1.25	0.035	0.049	
L4	0.60	1.00	0.024	0.039	
L5	0.15	0.75	0.006	0.030	
L6	1.80 REF		0.071	REF	
Φ	1.20	1.40	0.047	0.055	
θ	0°	8°	0°	8°	



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